International **ISR** Rectifier

PIIPM25P12B008

intero

Programmable Isolated IPM

PI-IPM Features:

Power Module:

- NPT IGBTs 25A, 1200V
- 10us Short Circuit capability
 - Square RBSOA
 - Low Vce_(on) (2.28Vtyp @ 25A, 25°C)
 - Positive Vce_(on) temperature coefficient
- Gen III HexFred Technology
 - Low diode V_F (1.76Vtyp @ 25A, 25°C)
 - Soft reverse recovery
- 4mΩ sensing resistors on all phase outputs and DCbus minus rail
 - Thermal coefficient < 50ppm/°C

Embedded driving board

- Programmable 40 Mips DSP
- Current sensing feedback from all phases
- Full protection from ground and line to line faults
- UVLO, OVLO on DCbus voltage
- Embedded flyback smps for floating stages (single 15Vdc @ 300mA input required)
- Asynchronous isolated 2.5Mbps serial port for DSP communication and programming
- IEEE standard 1149.1 (JTAG port interface) for program downloading and debugging
- Separated turn on / turn off outputs for IGBTs di/dt control
- Isolated serial port input with strobe signal for quadrature encoders or SPI communication

Description

The PIIPM25P12B008 is a fully integrated Intelligent Power Module for high performances Servo Motor Driver applications. The device core is a state of the art DSP, the TMS320LF2406A at 40 Mips, interfaced with a full set of peripherals designed to handle all analog feedback and control signals needed to correctly manage the power section of the device. The PIIPM has been designed and tailored to implement internally all functions needed to close the current, speed and position loops of a high performances servo motor driver.

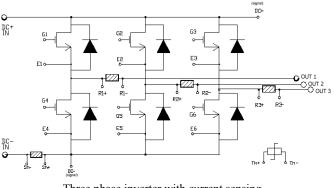
The use of the flash memory version of the DSP and the JTAG port connector allows the user to easily develop and download his own proprietary algorithm.

The device comes in the EMP^{TM} package, fully compatible in length, width and height with the popular EconoPack 2 outline.



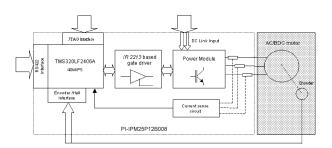
PI-IPM – Inverter (EconoPack 2 outline compatible)

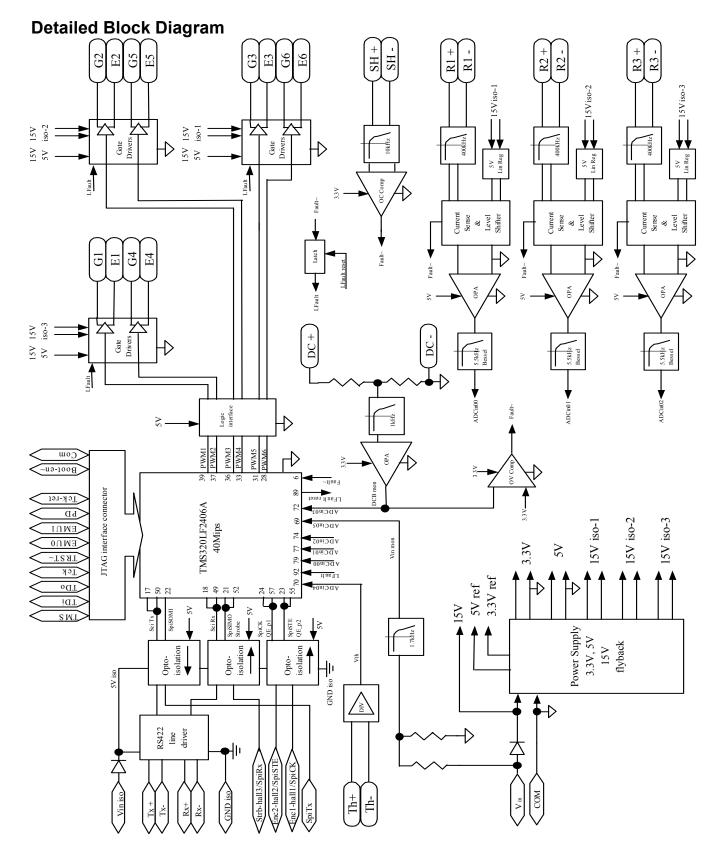
Power Module schematic:



Three phase inverter with current sensing resistors on all output phases and thermistor

PI-IPM System Block Schematic:





Signal pins on RS422 serial port

Symbol	Lead Description	Pin number	
Vin iso	External 5V supply voltage for opto-couplers and line driver supply	6	
GND iso	Extenal 5V supply ground reference for opto-couplers and line driver supply	7	
Tx+	RS422 Trasmitter Non inverting Driver Output	1	
Tx-	RS422 Trasmitter Inverting Driver Output	2	
Rx+	RS422 Receiver Non inverting Driver Input,	4	
Rx-	RS422 Receiver Inverting Driver Input	3	RS422
Enc1 – Hall1 / SpiCK	Incremental Encoder 1 / Hall effect sensor input 1/ SpiCK input (GND iso referenced)	5	serial
Enc2 – Hall2 / SpiSTE	Incremental Encoder 2 / Hall effect sensor input 2 / SpiSTE input (GND iso referenced)	9	port
Strb – Hall3 / SpiRx	Incremental Encoder Strobe / Hall effect sensor input 3 / SpiRx input (GND iso ref.). Also used for DSP boot feature using DSP boot ROM. Please see note below.	10	
SpiTx	SpiTx output (GND iso referenced)	8	
Vin	External 15V supply voltage. Internally referred to DC bus minus pin (DC -)	17-18	
COM	External 15V supply ground reference. This pin is directly connected to DC -	19-20	

Signal pins on IEEE1149.1 JTAG connector

CAUTION DO NOT APPLY DC BUS VOLTAGE WHEN JTAG INTERFACE IS CONNECTED, SEVERE DAMAGE WILL OCCUR ON POWER MODULE AND ON YOUR EQUIPMENT!

Symbol	Lead Description		Pin	number
TMS	JTAG test mode select	Input	12	
TMS2	JTAG test mode select 2	Input	5-6	
TDI	JTAG test data input	Input	14	
TDO	JTAG test data output	Output	13	
тск	JTAG test clock. TCK is a 10MHz clock source from the emulation pod. This signal can be used to drive the system test clock.	Input	15	
TRST~	JTAG test reset	Input	11	
EMU0	Emulation pin 0	I/O	9-10	
EMU1/OFF~	Emulation pin 1	I/O	7-8	IEEE1149.1
PD	Presence detect. Indicates that the emulation cable is connected and that the PI-IPM log ic is powered up. PD is tied to the DSP 3.3V supply through a 1k resistor.	Output	1	JTAG
TCK_RET	JTAG test clock return. Test clock input to the emulator. Internally short circuited to TCK.	Output	16	
Boot-En~	Boot ROM enable. This pin is sampled during DSP reset, pulling it low enables DSP boot ROM (Flash version only). 47k internal pull-up. Please see note below.	Input	17	
COM	Exernal 15V supply ground reference. This pin is directly connected to DC-	N/A	20	

¹ To enable DSP boot ROM for boot load feature through SCI at 40Mhz clock operation follow these steps:

¹⁾ Connect Boot-En~ to COM;

²⁾ Connect STR – Hall3 / SpiRx to GND iso;

³⁾ Apply voltage to Vin iso;

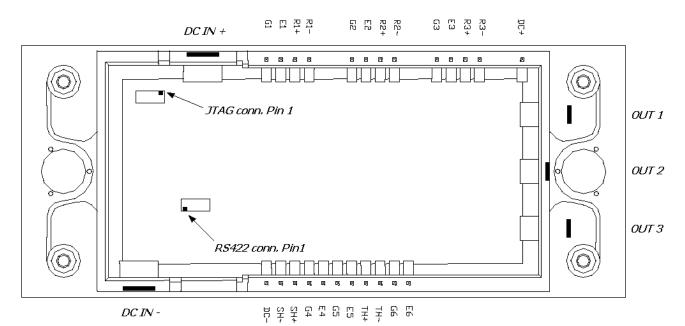
⁴⁾ Apply-voltage to Vin (after Vin iso to allow proper configuration).



Following pins are intended for signal communication between driving board and power module only, though here described for completeness, they are on purpose not available to the user.

Symbol	Lead Description	Pin number
DC +	DC Bus plus input signal	
DC -	DC Bus minus input signal (internally connected to COM)	
Th +	Thermal sensor positive input	
Th -	Thermal sensor negative input (internally connected to COM)	
Sh +	DC Bus minus series shunt positive input (Kelvin point)	
Sh -	DC Bus minus series shunt negative input (Kelvin point)	Lateral connectors
G1/2/3	Gate connections for high side IGBTs	- driving board
E1/2/3	Emitter connections for high side IGBTs (Kelvin points)	unving board
R1/2/3 +	Output current sensing resistor positive input (IGBTs emitters 1/2/3 side, Kelvin points)	
R1/2/3 -	Output current sensing resistor negative input (Motor side, Kelvin points)	
G4/5/6	Gate connections for low side IGBTs	
E4/5/6	Emitter connections for low side IGBTs (Kelvin points)	

Power Module Frame Pins Mapping





Absolute Maximum Ratings (T_C =25°C) Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to V_{DC-}, all currents are defined positive into any lead. Thermal Resistance and Power Dissipation ratings are measured at still air conditions.

	Symbol	Parameter Definition		Min.	Max.	Units	
	V _{DC}	V _{DC} DC Bus Voltage		0	1000	V	
	V _{CES}	Collector Emitter Voltage	0	1200	v		
	I _{C @ 100C}	IGBTs continuous collector current (T_c = 100 °C, fig. 1)			25		
	I _{C @ 25C}	IGBTs continuous collector current (T_c = 25 °C, fig 1)			50		
	I _{CM}	Pulsed Collector Current (Fig. 3, Fig. CT.5)			100	А	
Inverter	I _{F@100C}	Diode Continuous Forward Current (T _c = 100 °C)			25	~	
	I _{F @ 25C}	Diode Continuous Forward Current (T_c = 25 °C)			50		
	I _{FM}	Diode Maximum Forward Current			100		
	V _{GE}	Gate to Emitter Voltage		-20	+20	V	
	P _{D@25°C}	Power Dissipation (One transistor)			192	W	
	P _{D@100°C}	Power Dissipation (One transistor, T _c = 100 °C)			77	vv	
	V _{in}	Non isolated supply voltage (DC- referenced)		-20	20	V	
	V _{in-iso}	Isolated supply voltage (GND iso referenced)		-5	5.5		
Embedded	Rx	RS422 Receiver input voltage (GND iso referenced)		-7	12		
Driving	T _{AEDB}	Operating Ambient Temperature Range		-25	+70	°C	
Board	T _{STG-EDB}	Board Storage Temperature Range		-40	+125		
	V _{ISO-CONT} RS232	232 Input-Output Continuous Withstand Voltage (RH \leq 50%, -40°C \leq T _A \leq 85°C) AC DC		800 1000		V V	
	V _{ISO-TEMP} RS232	Input-Output Momentary Withstand Voltage (RH \leq 50%, t = 1 min, T _A = 25°C) RMS		2500		V	
					3.5	Nm	
Power				-40	+150	°C	
Module				-40	+125	0	
	Vc-iso	Isolation Voltage to Base Copper Plate		-2500	+2500	V	



Electrical Characteristics: Inverter

For proper operation the device should be used within the recommended conditions.

T_J = 25°C (unless otherwise specified)

Symbol	Parameter Definition	Min.	Тур.	Max.	Units	Test Conditions	Fig.
V _{(BR)CES}	Collector To Emitter Breakdown Voltage	1200			V	$V_{GE} = 0V, I_{C} = 250 \mu A$	
$\Delta V_{(BR)CES/\Delta T}$	Temperature Coeff. of Breakdown Voltage		+1.2		V/°C	V _{GE} = 0V, I _C = 1mA (25 - 125 °C)	
			2.28	2.56		I _C = 25A, V _{GE} = 15V	5, 6
V _{CE(on)}	Collector To Emitter Saturation Voltage		3.2	3.65	V	I _C = 50A, V _{GE} = 15V	7, 9
			2.74	3.10		I _C = 25A, V _{GE} = 15V, T _J = 125 °C	10, 11
V _{GE(th)}	Gate Threshold Voltage	4.0	5.0	6.0	V	V_{CE} = V_{GE} , I_C = 250 μ A	- 12
$\Delta V_{\text{GE(th)}/\Delta \text{Tj}}$	Temp. Coeff. of Threshold Voltage		-1.2		mV/°C	V _{CE} = V _{GE} , I _C = 1mA (25 - 125 °C)	12
g _{fe}	Forward Trasconductance	14.8	16.9	19.0	S	V _{CE} = 50V, I _C = 25A, PW = 80µs	
				250		V _{GE} = 0V, V _{CE} = 1200V	
I _{CES}	Zero Gate Voltage Collector Current		325	675	μA	V _{GE} = 0V, V _{CE} = 1200V, T _J = 125 °C	
				2000		V _{GE} = 0V, V _{CE} = 1200V, T _J = 150 °C	
V	Diode Forward Voltage Drop		1.76	2.06	V	I _C = 25A	8
V _{FM}	Didde Forward Voltage Drop		1.87	2.18	v	I _C = 25A, T _J = 125 °C	8
I _{RM}	Diode Reverse Leakage Current			20	μA	V _R = 1200V, T _J = 25 °C	
I _{GES}	Gate To Emitter Leakage Current			±100	nA	V _{GE} =± 20V	
R1/2/3	Sensing Resistors	3.96	4	4.04	mΩ		
Rsh	DC bus minus series shunt resistor	3.96	4	4.04	1115.2		



Switching Characteristics: Inverter For proper operation the device should be used within the recommended conditions. $T_J = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter Definition	Min	Тур	Max	Units	Test Conditions	Fig.	
Qg	Total Gate Charge (turn on)		169	254		I _C = 25A	23	
Q _{ge}	Gate – Emitter Charge (turn on)		19	29	nC	V _{CC} = 600V	-	
Q _{gc}	Gate – Collector Charge (turn on)		82	123		V _{GE} = 15V	CT1	
Eon	Turn on Switching Loss		1900	3600		I _C = 25A, V _{CC} = 600V, T _J = 25 °C	CT4	
E _{off}	Turn off Switching Loss		1300	2000	μJ	V_{GE} = 15V, R_{G} =22 Ω , L = 200 μ H	WF1	
E _{tot}	Total Switching Loss		3200	5600		Tail and Diode Rev. Recovery included	WF2	
E _{on}	Turn on Switching Loss		2700	4600		$I_{\rm C}$ = 25A, $V_{\rm CC}$ = 600V, $T_{\rm J}$ = 125 °C	13,	
E _{off}	Turn off Switching Loss		2000	2300	μJ	V _{GE} = 15V, R _G =22Ω, L = 200μH	15 CT4	
E _{tot}	Total Switching Loss		4700	6900		Tail and Diode Rev. Recovery included	WF1 WF2	
td (on)	Turn on delay time		192	210			14,16	
Tr	Rise time		33	49		I _C = 25A, V _{CC} = 600V, T _J = 125 °C	CT4	
td (off)	Turn off delay time		213	227	ns		WF1	
Tf	Fall time		210	379		V_{GE} = 15V, R_{G} =22 Ω , L = 200 μ H	WF2	
C _{ies}	Input Capacitance		2200			V _{cc} = 30V		
C _{oes}	Output Capacitance		210		PF	$V_{GE} = 0V$	22	
C _{res}	Reverse Transfer Capacitance		85			f = 1MHz		
RBSOA	Reverse Bias Safe Operating Area	F	ULL SQUAF	RE		$T_J = 150 \text{ °C}, I_C = 100 \text{ A}, V_{GE} = 15 \text{ V to } 0 \text{ V}$	4 CT2	
						$V_{cc} = 1000V, V_p = 1200V, R_G = 5\Omega$	CT3	
SCSOA	Short Circuit Safe Operating Area	10			μs	$T_{J} = 150 \text{ °C}, V_{GE} = 15V \text{ to } 0V$		
		_				V_{CC} = 1000V, Vp= 1200V, R _G = 5 Ω	WF4	
E _{REC}	Diode reverse recovery energy		1820	2400	μJ	T _J = 125 °C	17,18 19,20	
Trr	Diode reverse recovery time		300		ns	I _F = 25A, V _{CC} = 600V,	21 CT4	
Irr	Peak reverse recovery current		25	32	A	V_{GE} = 15V, R_{G} =22 Ω , L = 200 μ H	WF3	
Rth_{JC_T}	Each IGBT to copper plate thermal resistance			0.65	°C/W			
Rth_{JC_D}	Each Diode to copper plate thermal resistance			0.95	°C/W	See also fig. 24 and 25	24,25	
Rth _{c-H}	Module copper plate to heat sink thermal resistance. Silicon grease applied = 0.1mm			0.03	°C/W			
			52			$\rm I_{C}$ = 3.5A, $\rm V_{DC}$ = 530V, fsw = 8kHz, T_{C} = 55 °C	PD1	
Pdiss	Total Dissipated Power		70		w	$I_{\rm C}$ = 5A, $V_{\rm DC}$ = 530V, fsw = 8kHz, $T_{\rm C}$ = 55 °C	PD2	
			114			$I_{\rm C}$ = 5A, $V_{\rm DC}$ = 530V, fsw = 16kHz $T_{\rm C}$ = 55 °C,	PD3	
			102			I_{C} = 10A, V_{DC} = 530V, fsw = 4kHz, T_{C} = 40°C	гIJЭ	

Electrical Characteristics: Embedded Driving Board (EDB) communication ports For proper operation the device should be used within the recommended conditions. Vin = 15V, Vin-iso = 5V, $T_A = 0$ to 55C, $T_C = 75C$ (unless otherwise specified)

Symbol	Parameter Definition	Min.	Тур.	Max.	Units	Test Conditions	Conn.
Vin	EDB Input supply Voltage	12	15	18	V		
lsupp	EDB input Supply Current with EEprom not programmed	90	100	110	mA		
lsupp	EDB input Supply Current	126	139	151	mA	V _{DC} = 0V, f _{PWM} = 8kHz(*)	
lsupp	EDB Input Supply Current	130	147	163	mA	V _{DC} = 600V, f _{PWM} = 8kHz(*)	
Vin iso	EDB isolated supply voltage	4.5	5	5.5	V		RS422 port
lq. iso	EDB isolated quiescent supply current		9	20	mA	Rx+ = +5V, Rx- = 0V Hall1/2/3 = open	
launn ico	EDB isolated supply current	24	29	34	mA	Hall1/2/3 low Rx+ = 0V, Rx- = +5V Tx+ and Tx- open	
Isupp. iso	EDB Isolated Supply Current	37	48	59	mA	Hall1/2/3 low Rx+ = 0V, Rx- = +5V Tx+ and Tx- on 120Ω	
V _{DO-TX}	Differential Driver Output Voltage	2			V	- Rload = 120 Ω	
V _{CO-TX}	Driver Common mode output voltage			3	V		
V _{DI-RX}	Receiver Input Differential Threshold Voltage	- 0.2		0.2	V		RS422 port
R _{IN-RX}	Receiver Input Resistance		120		Ω	$-7V \leq V_{CM} \leq +12V$	
f _{MAX}	RS422 maximum data rate			2.5	Mbps		
Venc-high / Vhall-high	Logic High Input Voltage	3.6			V	Enc1 / Hall1	
Venc-low / Vhall-low	Logic Low Input Voltage			2	V	Enc2 / Hall2 Strb / Hall3	RS422 port
lenc-low / lhall-low	Logic Low Input Current	- 5.2			mA	input pins	
TMS, TDI, TDO, TMS2, TCK, TRST~, EMU0, PD, EMU1/OFF~	JTAG inf ² erface pins (CAUTION DO NOT APPLY DC BUS VOLTAGE WHEN JTAG INTERFACE IS CONNECTED, SEVER DAMAGE WILL OCCUR ON POWER MODULE AND ON YOUR EQUIPMENT!)	d: Tex	Please see S320LF240 atasheet from as Instrume / _{PD} specifica	6A m ents		Directly connected from DSP to connector pins. EMU0 and EMU1 with 4.7k internal pull up.	JTAG
V _{PD}	Presence detect voltage	3.2	3.3	3.4	V	I _{PD} = -100μA	JTAG
V _{Boot En~}	Boot ROM enable input voltage			0.5	V	Active low	JTAG
I _{Boot-En~}	Boot ROM enable input current			- 100	μΑ		UIAG

² these values are obtained with internal DSP clock, EVA, EVB, SCI peripherals enabled at 40MHz, A/D peripheral at 20MHz and 50% PWM duty cycle on all legs.

AC Electrical Characteristics: Embedded Driving Board (EDB)

DSP pins mapping

For proper operation the device should be used within the recommended conditions. Vin = 15V, Vin-iso = 5V, $T_A = 0$ to 55C, $T_C = 75C$ (unless otherwise specified)

Symbol	Parameter Definition	Min.	Тур.	Max.	Units	Test Conditions	DSP name ; pin N
V_{DCgain}	DC bus voltage feedback partition coefficient	2.39	2.44	2.49	mV/V		
V_{DCpole}	DC bus voltage feedback filter pole	950	1000	1050	Hz		ADCin03;72
$V_{\text{DC-MAX}}$	Maximun DC bus voltage read	1309			V		
$V_{\text{DC-OVth}}$	DC bus voltage over-voltage threshold	870	920	970	V		PDPINTA;6
V_{TH25C}	Thermal sensor voltage feedback at 25 °C (Fig. TF1)	2.65	2.75	2.85	V		ADCin04:70
V _{TH100C}	Thermal sensor voltage feedback at 100 °C (Fig. TF1)	1.04	1.09	1.14	V		ADCIII04,70
Vin-gain	Input voltage feedback partition coefficient	125	128	131	mV/V		
Vin-pole	Input voltage feedback filter pole	1600	1700	1800	Hz		ADCin05;69
lph- _{GAIN}	Current feedback gain	33.2	33.8	34.4	mV/A		
Iph- _{pole}	Current feedback filter pole	5.0	5.5	6.0	kHz		
Iph- _{MAX}	Maximun Current feedback read	47			А	all phases	ADCin00: 79
Iph- _{MIN}	Minimun Current feedback read			-47	А		ADCin01: 77 ADCin02: 74
lph- _{LAT}	Current feedback signal delay			12	μs		ADGII02.74
lph- _{Zero}	Zero current input voltage level	1.64	1.67	1.70	V		
I _{SC}	Short Circuit Threshold Current	110	128	146	А	all phases	
I _{SC-DEL}	Short Circuit detection delay time		3	6	μs	all phases	PDPINTA;6
DC _{oc}	DC bus minus over-current level	130	140	150	А	DC bus minus	
$DC_{OC\text{-pole}}$	DC bus minus over-current filter pole	14	15	16	kHz	DC bus minus	PDPINTA;6
WD	External watchdog timeout (see also RS~ signal)	0.9	1.6	2.5	Sec		WD;85
СОМ	DSP Ground	2, 3, 5, 7, 11, 12, 13, 14, 15, 16, 19, 26, 27, 29, 32, 34, 38, 41, 43, 45, 46, 48, 53, 56, 58, 60, 63, 65, 66, 67, 68, 71, 73, 75, 76, 78, 80, 81, 84, 90, 97					
3.3V	DSP 3.3V supply	4, 10, 20, 30, 35, 47, 54, 59, 64, 91, 98					
floating	The following pins are left unconnected					42,44,51,88	
Ref3.3V	3.3V reference voltage		3.33			V	

International **TGR** Rectifier

Other DSP pins mapping

Symbol	Signal Definition	DSP pin name ;pin N	Comments
PWM1	OUT 1 high side IGBT gate drive signal	PWM1;39	DSP Event Manager A output
PWM2	OUT 1 low side IGBT gate drive signal	PWM2;37	DSP Event Manager A output
PWM3	OUT 2 high side IGBT gate drive signal	PWM3;36	DSP Event Manager A output
PWM4	OUT 2 low side IGBT gate drive signal	PWM4;33	DSP Event Manager A output
PWM5	OUT 3 high side IGBT gate drive signal	PWM5;31	DSP Event Manager A output
PWM6	OUT 3 low side IGBT gate drive signal	PWM6;28	DSP Event Manager A output
Enc1–Hall1 / SpiCK	Incremental Encoder 1 / Hall effect sensor input 1/ SpiCK input (GND iso referenced)	SPICK;24 QEP1;57	Optically isolated input
Enc2 – Hall2 / SpiSTE	Incremental Encoder 2 / Hall effect sensor input 2 / SpiSTE input (GND iso referenced)	SPISTE~;23 QEP2; 55	Optically isolated input
Strb – Hall3 / SpiRx	Incremental Encoder Strobe / Hall effect sensor input 3 / SpiSIMO input (GND iso ref.)	SPISIMO;21 CAP3; 52	Optically isolated input
SpiTx	SpiSOMI output (GND iso referenced)	SPISOMI;22	Optically isolated input
Ref3.3V	3.3V reference voltage	Vrefhi;82 Vcca; 83	3.33V reference voltage for ADC converter
5V supp.	Flash programming voltage pin	Vccp;40	Supplied by the embedded flyback regulator
Boot En~	Boot ROM enable signal	BOOT_EN~;86	See also EDB electrical characteristics
Tx	SCI transmit data	SCITXD;17 CANTX ; 50	Drives Tx+ and Tx- through an opto-isolator and a line driver
Rx	SCI receive data	SCIRX ; 18 CANRX ; 49	Driven by Rx+ and Rx- through an opto-isolator and a line driver
LFAULT	System general fault input (latched)	IOPF6;92	Activated by short circuits on output phases and DC bus minus and by DC bus over-voltage comparator
LFAULT reset	System general fault output reset signal	IOPF5;89	LFAULT Reset signal, to be activated via software after a fault or system boot
FAULT~	System general fault input (not latched)	PDPINTA~;6	Activated by short circuits on output phases and DC bus minus and by DC bus over-voltage comparator
RS~	DSP reset input signal (see also WD signal)	RS~;93	Forces a DSP reset if WD signal holds too long (see also EDB electrical char.)
Xtal1	PLL oscillator input pin	XTAL1;87	A 10Mhz oscillator at 100ppm frequency stability feeds this pin.
PLLF1	PLL filter input 1	PLLF;9	PLL filter for 40Mhz DSP clock frequency
PLLF2	PLL filter input 2	PLLF2;8	PLL filter for 40Mhz DSP clock frequency
PDPINTB	External protection interrupt for EVB	PDPINTB~;95	Not used pull up 4.7K to 3.3V
	s active low signals		

General Description

The PI-IPM is a new generation of Intelligent Module designed specifically to Power implement itself a complete motor driver system. The device contains all peripherals needed to control a six IGBTs inverter, including voltage, temperature and current output sensing, completely interfaced with a 40Mips DSP, the TMS320LF2406A from Texas Instruments. All communication between the DSP and the local host, including DSP software installing and debugging, is realized through an asynchronous isolated serial port (SCI), an isolated port for incremental encoder inputs or synchronous serial port communication (SPI) is also provided module a complete making this user programmable solution connected to the system only through a serial link cable.

System Description

The PI-IPM is realized in two distinct parts: the Power Module "EMP" and the Embedded Driving Board "EDB," these two elements assembled together constitute the complete device with all performances described in the following.

The complete block schematic showing all functions implemented in the product is represented on the System Block Schematic on page 1. The new module concept includes everything depicted within the dotted line, the EMP power module includes IGBTs, Diodes and Sensing Resistors while all remaining electronics is assembled on the EDB that is fitted on the top of it as a cover with also mechanical protective functions.

Connections between the two parts are realized through a single-in-line connector and the EDB only, without disassembling the power module from the system mechanic, can be easily substituted "at the factory" for an upgrade, a system configuration change (different control architecture) or a board replacement. Also software upgrades are possible but this does not even require any hardware changes thanks to the DSP programmability through the serial or JTAG ports.

International **ISPR** Rectifier

THE "EMPTM" POWER MODULE

This module contains six IGBTs + HexFreds Diodes in a standard inverter configuration. IGBTs used are the new NPT 1200V-25A (current rating measured @ 100C), generation V from International Rectifier; the HexFred diodes have been designed specifically as pair elements for these power transistors. Thanks to the new design and technologic realization, this gen V devices do not need any negative gate voltage for their complete turn off and the tail effect is also substantially reduced compared to competitive devices of the same family. This feature simplifies the gate driving stage that will be described in a dedicated chapter. Another not standard feature in this type of power modules is the presence of sensing resistors in the three output phases, for precise motor current sensing and short circuit protections, as well as another resistor of the same value in the DC bus minus line, needed only for device protections purposes. A complete schematic of the EMP module is shown on page 1 where sensing resistors have been clearly evidenced, a thermal sensor is also embedded and directly coupled with the DSP inputs.

The package chosen is mechanically compatible with the well known EconoPack outline, also the height of the plastic cylindrical nuts for the external PCB positioned on its top is the same, so that, with the only re-layout of the main motherboard, this module can fit into the same mechanical fixings of the standard Econo II package thus speeding up the device evaluation in an already existing driver.

An important feature of this new device is the presence of Kelvin points for all feedback and command signals between the board and the module with the advantage of having all emitter and resistor sensing independent from the power path. The final benefit is that all low power signal from/to the controlling board are unaffected by parasitic inductances or resistances inevitably present in the module power layout. The new package outline is show on page 4, all signal and power pins are clearly listed, note that because of high current spikes on those inputs the DC bus power pins are doubled in size comparing to the other power pins. Module technology uses the standard and well know DBC: over a thick Copper base an allumina (Al₂O₃) substrate with a 300µm copper foil on both side is placed and IGBTs and Diodes dies are directly soldered, through screen printing process. These dies are then bonded with a 15 mils aluminum wire for power and signal connections. All components are then completely covered by a silicone gel with mechanical protection and electrical isolation purposes.

THE "EDB" EMBEDDED DRIVING BOARD

This is the core of the device intelligence, all control and driving functions are implemented at this level, the board finds its natural placement as a cover of the module itself and has a double function of mechanical cover and intelligent interface. DSP and all other electronics are here assembled; figure on page 2 shows the board schematic and all connection pins.

Looking at the schematic, all diamond shaped pins are signal connections, some belonging to the RS422 port interface and some to the IEEE 1149.1 (JTAG) connector. All other pins are used for communication between the board and the module, they are positioned laterally in the board and the module doesn't have any pins in the middle of its body.

From the top left, in anti-clockwise direction we identify the following blocks that will be then described in details:

- 1. DSP and opto isolated serial and JTAG ports
- 2. Flyback Power Supply
- 3. Current Sensing interfaces, over-current protections and signal conditioning
- 4. Gate drivers
- 5. DC bus and Input voltage feedback

1. DSP and opto isolated serial and JTAG ports.

The DSP used in this application is the new TMS320LF2406A from TI, it is a improvement of the well known in the motor driver market "F240" used in many motor driver applications. If we compare this new device with the predecessor, the new DSP has some added features that let the software designer significantly improve the system control performances, the following table shows a list of relevant data, for all other information please refer to the related device datasheet. To be noted is the increased number of instruction per second, (40MIPS) and of I/O pins, the availability of a boot ROM and a CAN, a much faster ADC and the reduced supply voltage from 5V down to 3.3V, to follow the global trend for this type of products. The choice of the DSP has been done looking at the high number of applications already existing in the market using devices of this family, however it is clear that the same kind of approach could be followed using products from different suppliers to let the customer work on its preferred and well known platform.

TMS320LF2406A vs TMS320F240

	'F2406	'F240
MIPS	40	20
RAM	2.5Kw	544w
Flash	32Kw	16Kw
ROM	_	
Boot ROM	256w	
Ext. Memory I/F	_	Yes
Event manager	Yes	Yes
• GP timers	4	3
• CMP/PWM	10/16	9/12
• CAP/QEP	6/4	4/2
Watchdog timer	Yes	Yes
10-bit ADC	Yes	Yes
Channels	16	16
• Conv. time (min)	500ns	6.6µs
SPI	Yes	Yes
SCI	Yes	Yes
CAN	Yes	
Digital I/O pins	37	28
Voltage range	3.3V	5 V

The "2406A" has three different serial interfaces available: SCI, SPI, and CAN bus. In the PI-IPM25P12B008 communication is made through the asynchronous port (SCI) while four other opto-isolated lines can be used for the SPI or for the hall effect sensor interface. Maximum bit rate for this asynchronous serial port is 2.5Mbps while the SPI (synchronous) could reach 10Mbps. The choice of the SCI has been taken for easy interfacing with a standard computer serial port, the only component needed is a line driver to adapt the RS232 voltage standard with the RS422 at 3.3V used on this application.

In a standard Brushless motor application usually 1Mbps are far enough to transmit all information needed for the torque reference updates and other fault and feedback signals at a maximum frame rate of 10kHz (100bits/frame), in this way the onboard line driver let the application use long connecting wires between the host and the module, leaving the user the possibility of having the PI-IPM displaced near the motor, e.g. in its connecting box, thus avoiding long ad noisy three phase cables between driver and load.

The JTAG port is the standard one, neither isolation nor signal conditioning are provided here and all signal, except the Tck-ret, are directly connected from the related DSP pins to the connector; however, due to the limited board space, the connector used in not the standard 14 pins at two rows header, then an adaptor has to be realized to connect it to the JTAG adapter interface provided by Texas Instruments.

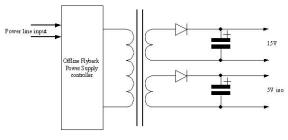
Last but not least is the ADC speed and load characteristic: as the table shows the conversion time is 500ns, in fact the 2406A DSP has a single ADC handling, in time sharing, all 16 inputs, then, using 6 inputs, the total conversion time, which is a fixed delay to wait for before having all data updated, is around $3.0\mu s$.

2. Flyback Power Supply

A flyback power supply for the floating stages is provided in the EDB. As the block schematic on page 2 shows, we have three 15V outputs for the floating stages, isolated from each other at 1.5kV minimum, and a single 5V and 3.3V output.

International **TOR** Rectifier

The 5V supplies all low voltage electronics and a 3.3V linear regulator is used to feed the DSP and some analog and logic interfaces to it. This 5V and 3.3V are directly referred to the DC bus minus, so that all control circuitry is alternately at one of the input lines potential, isolation is provided at the DSP serial link level, then avoiding all delays due to opto couplers insertion between DSP and control logic. Note that also the required 15V input voltage is referred to the same DC bus minus and directly supplies the low side gate drivers stages, the user should pay some attention on how this supply line is realized in his application. Just for completeness, the following figure gives a possible solution to that that doesn't impact heavily on the user application.



Examples of power supply for PI-IPM 15V and 5V iso inputs

Normally a 5V power supply is already present, for displays, electronics and micro processor, the same 5V could be used for the 5V iso supply of opto-couplers and line driver, the 15V could be realized as an added winding in the secondary side of the flyback transformer, the only care that should be taken is in keeping its isolation from the above mentioned 5V at the required level (at least 1.5kV).

To avoid noise problems in the measuring lines due to the commutating electronics during normal functioning of the system, references are kept separated. A 5V linear regulator, directly supplied from the 15V input, is used to provide the reference voltage to the current sensing amplifying and conditioning components while a precise op-amp, configured as a voltage follower, acts as a buffer of the partition at 3.30V created down the 5V reference. This 3.30V is used also as reference for the DSP A/D converter. It has to be noted that in the schematic we are using the same linear regulator as a starting point for all reference voltages. In fact if the 5V linear regulator drifts in temperature or time, then all references (even the 3.30V being this a simple partitioning) follow in track and still keep the overall chain precision. The trimming is then done only once, in a single point of the measuring chain, that is the conditioning op-amp collecting the current sensing ICs signal as will then be described in the following chapter.

3. Current sensing interfaces, over-current protections and signal conditioning.

This block is the real critical point of the system. Current measuring performances directly impact on motor control performances in a servo application: errors in current evaluation, delay in its measuring chain or poor overall precision of the system, such as scarce references or lower number of significant A/D bits, inevitably results in unwanted trembling and unnatural noise coming from the motor while running at lower speed or at blocked shaft conditions.

In the PI-IPM25P12B008 the current sensing function is done through three sensing resistors dropout measurement, one on each output phase, with the benefit of a lower area and somewhat a lower cost compared to the well-known Hall effect devices. This solution has the added value of having the shunts element embedded in the power module with all Kelvin connections available, avoiding any noise due to long routing of power paths.

As the block schematic on page 2 shows, the voltage across each sensing resistor is applied, through an anti-aliasing 400kHz filter, at the input of a current sense IC and then to a signal conditioning circuit.

Though the block schematic here shows an Op-Amp plus an external passive filter this is simply realized implementing a VCVS cell (i.e. a Constant Gain or Sallen – Key cell) configured so that the offset and gain is easily trimmed by three on board resistors. The filter implemented is a second order Bessel with 5.5kHz pole frequency, the reason for this is that this type of polynomials are calculated with the aim of having a constant group delay within the pass-band frequencies, thus giving the minimum waveform distortion to the output signal up to almost twice the filter www.irf.com

International

pole. In other words we could also say that the group delay of the signal chain from the sensing resistor up to the ADC input of the DSP is constant from 0 to 5.5kHz.

Signal outputted from the overall chain has a 0 to +3.30V dynamic, with a sensing resistor of 4mohms the input measured current range is +/-50A then we have a situation as follows:

$$-50A = 0.0V$$

 $0.00A = 1.65V$
 $+50A = 3.30V$

Summing up our current measurements performances are shown in the following table:

PI-IPM Current sensing chain typical performances

	Value	Units
current range	+/- 50	А
Gain and Offset precision	+/- 1.8	%
bandwidth	5.5	kHz
latency time	10	μs

The "2406A" DSP has a 10bit ADC, consequently the PI-IPM25P12B008 has a minimum appreciable current step of approximately:

$$LSB = \frac{2*50}{2^{10}} = 0.0976A$$

that is: $1LSB \cong 98mA$

The over current protection is provided also through the current sensing ICs, the related fault signal is activated when a 250mV voltage across sensing pins is detected, this means an overcurrent detection level of approximately 25%. The delay of this line is around 3μ s, fast enough to let the DSP react within the 10 μ s IGBTs short circuit rating, thus providing full device protection for any phase-to-ground and phase-tophase short circuits. The only failure not covered in this way is the shoot-through, where high current levels cannot be detected from outside the module rather internally between two IGBTs of the same leg. In this case the protection is implemented by means of the fourth sensing element, with the same resistive value of the other shunts present in the power module, inserted in series to the DC bus minus. The related dropout voltage is then filtered by a 15kHz passive filter to avoid false fault detections due to unwanted induced voltage spikes and finally applied to an operational amplifier configured as a comparator. All data referred to the OC protection are listed on page 9 of this datasheet.

4. Gate Drivers

Devices used to perform this task are the wellknown IR2213, capable of 2A sink and 2A source maximum gate driving current, in a SO16W package; on page 2 is shown also the block schematic of the gate driving section of the module.

The IGBTs used in the PI-IPM (genV NPT 1200V - 25A from IR) do not need any negative gate drive voltage for their complete turn off, this simplifies the flyback power supply design avoiding the need of center tapped transformer outputs or the use of zener diodes to create the central common reference for the gate drivers floating ground. Though the IR2213 do have +/-2A of gate current capability, in the PI-IPM25P12B008 we use different gate resistor values for turn on and turn off as follows:

turn - on = 68ohmturn - off = 22ohm

Commonly realized through a diode-resistor series in parallel with a single resistor used in turn on only. Observed rise and fall times are around 250ns – 300ns depending on the output current level, this values are considered as pretty adequate for a 12.5A application at 16kHz symmetric PWM carrier, space vector modulation.

International

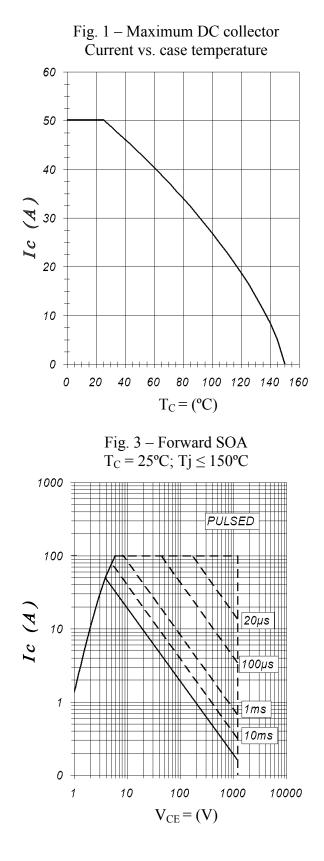
These gate drivers do provide levels shifting without any galvanic isolation, that is no optocouplers are built inside. This turns out to be a major benefit in this stage where the usual 1µs delay of optos impacts on the system control as a systematic and fastidious delay.

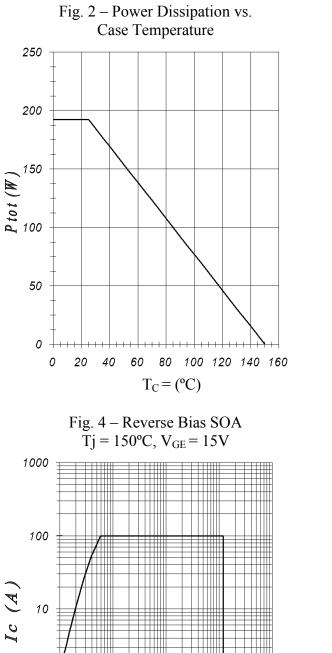
5. DC bus and Input voltage feedback

The purpose of this block is to continuously check the voltage of the two supply lines of the system: Vin and DC bus. Vin is the only external power supply needed for all electronics in the EDB. The internal flyback regulator has its own under-voltage lockout to prevent all electronics from start working when an insufficient supply voltage is present; minimum recommended supply voltage is 12V. Low side gate drivers are directly fed from the Vin line and there is no further control to this voltage than their own under-voltage lockout. This is typically set at 8.5V and this level could be not sufficient to properly drive the IGBT gates, then it is advisable to check with the DSP the input voltage and impose that the system could start switching only when the Vin voltage is between 10V and 18V thus providing also an over-voltage control.

The DC bus voltage is also important for the system functioning and needs to be continuously kept under control. A resistor divider provides a partition coefficient of 2.44mV/V and a maximum mapped voltage of around 1100V

As the block schematic shows, it has to be taken into account that, to avoid false detections due to voltage spikes inevitably present on the partitioned voltage, a 1kHz passive filter has been inserted between the divider and the voltage follower buffer whose output is connected to one of the ADC inputs.





1

0

1

10

100

 $V_{CE} = (V)$

1000

International **1©R** Rectifier

10000

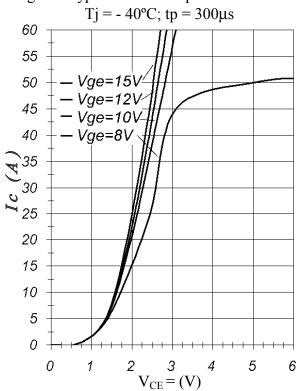


Fig. 7 – Typical IGBT Output Characteristics $T_{j} = 125^{\circ}C; tp = 300 \mu s$

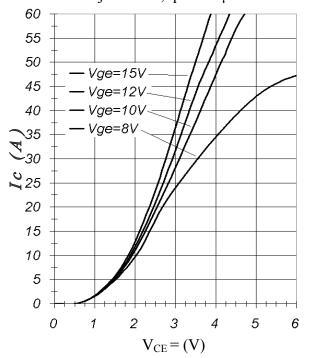
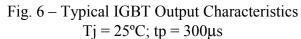


Fig. 5 – Typical IGBT Output Characteristics





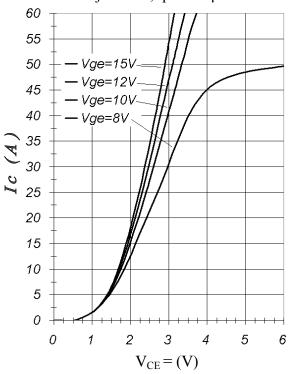
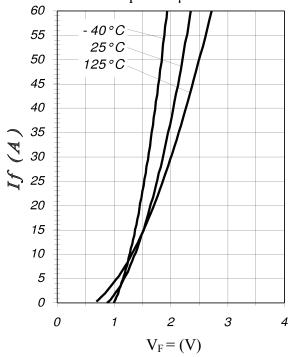
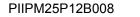
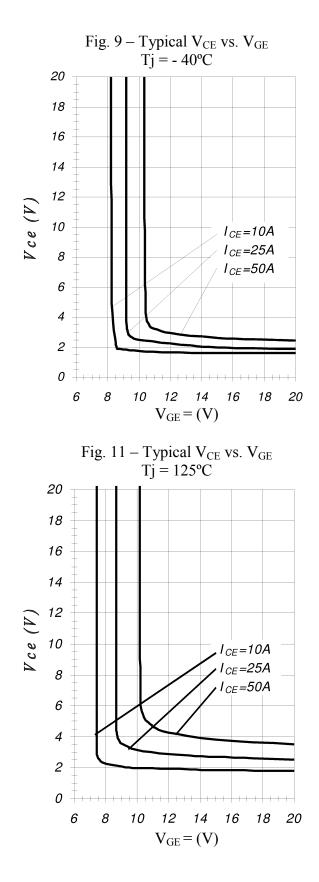


Fig. 8 – Typical Diode Forward Characteristics $tp = 300 \mu s$







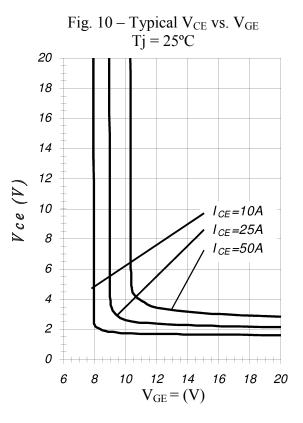
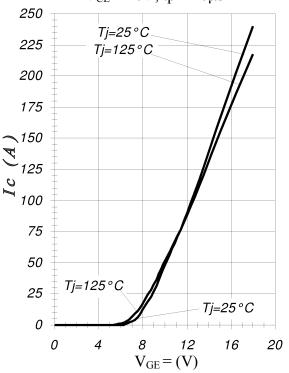


Fig. 12 – Typical Transfer Characteristics $V_{CE} = 20V$; tp = 20µs



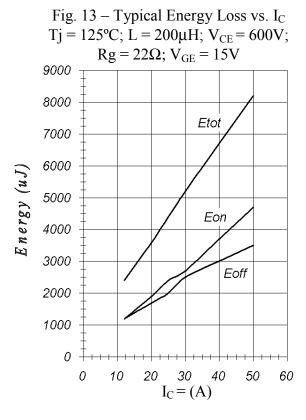
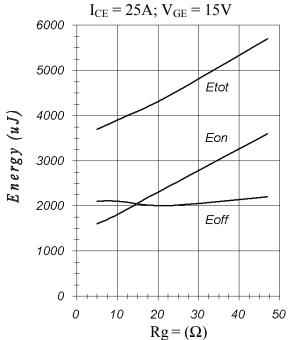


Fig. 15 – Typical Energy Loss vs. Rg Tj = 125°C; L = 200 μ H; V_{CE} = 600V;



International

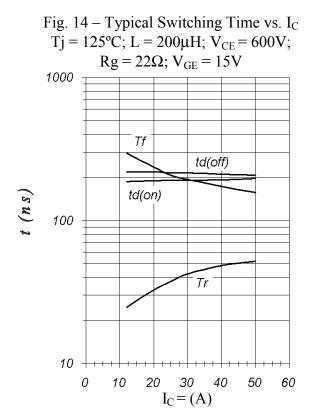
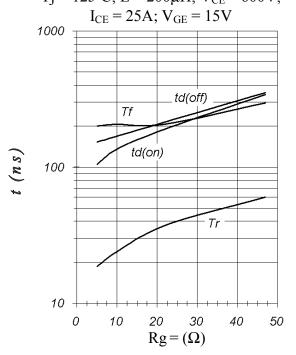


Fig. 16 – Typical Switching Time vs. Rg Tj = 125° C; L = 200μ H; V_{CE} = 600V;



www.irf.com

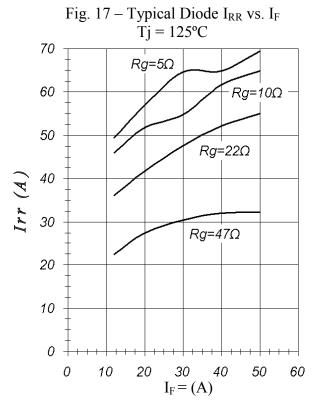
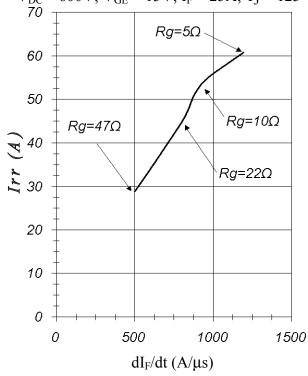
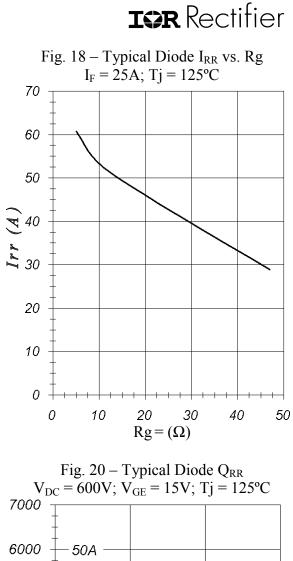
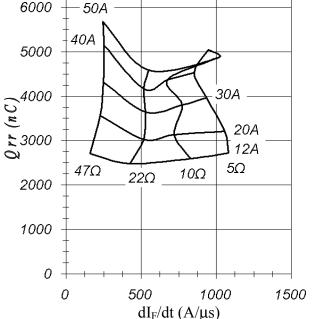


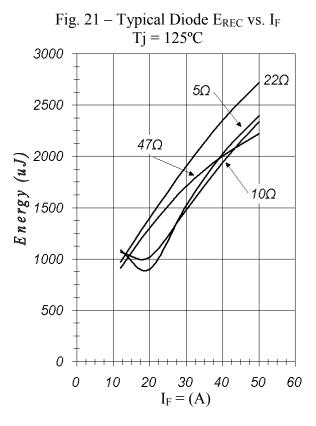
Fig. 19 – Typical Diode I_{RR} vs. dI_F/dt V_{DC} = 600V; V_{GE} = 15V; I_F = 25A; Tj = 125°C

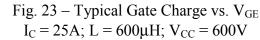


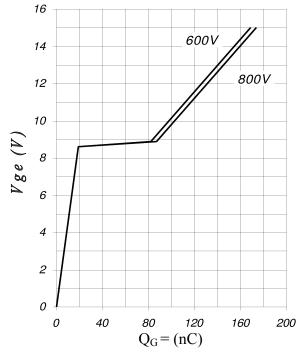


International

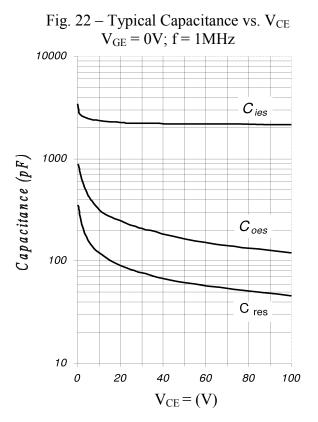








International **197** Rectifier



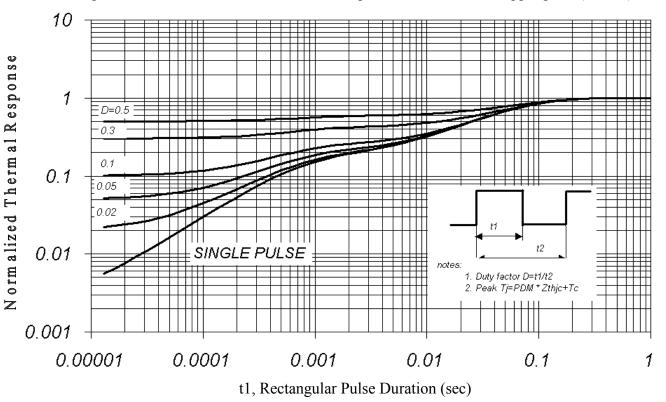


Fig. 24 – Normalized Transient Thermal Impedance, Junction-to-copper plate (IGBTs)

ICR Rectifier

Fig. 25 – Normalized Transient Impedance, Junction-to-copper plate (FRED diodes) 10 Normalized Thermal Response 1 D=0.5 0.3 0.1 0.1 0.05 0.02 ±1 t2 SINGLE PULSE 0.01 notes: 1. Duty factor D=t1/t2 ПП 2. Peak Tj=PDM * Zthjc+Tc 0.001 0.00001 0.001 0.01 0.0001 0.1 1

Fig. CT.1 - Gate Charge Circuit (turn-off)

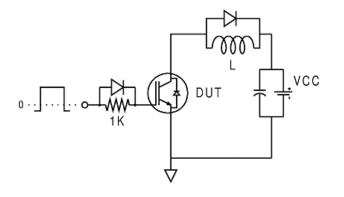


Fig. CT.2 - RBSOA Circuit

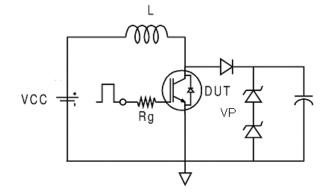


Fig. CT.3 - S.C. SOA Circuit

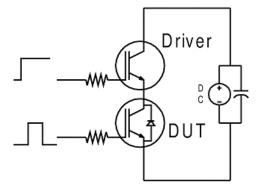


Fig. CT.4 - Switching Loss Circuit

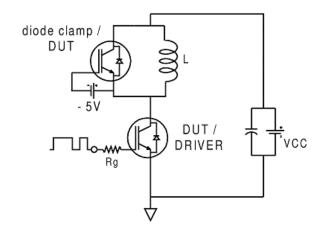
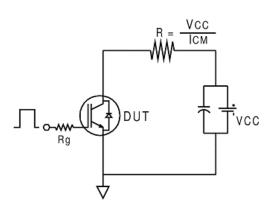


Fig. CT.5 - Resistive Load Circuit



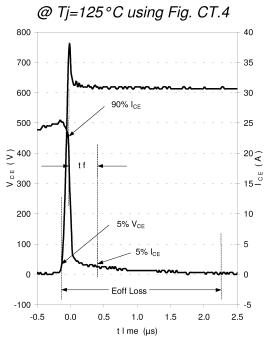
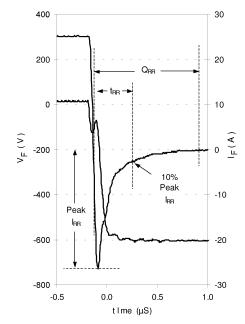
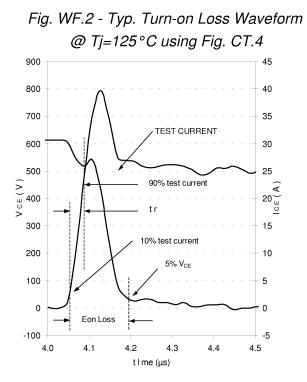


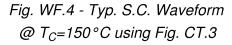
Fig. WF.1 - Typ. Turn-off Loss Waveform

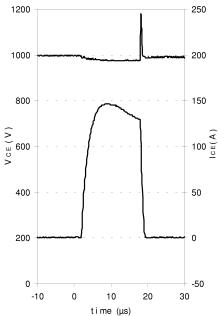
Fig. WF.3 - Typ. Diode Recovery Waveform @ Tj=125°C using Fig. CT.4

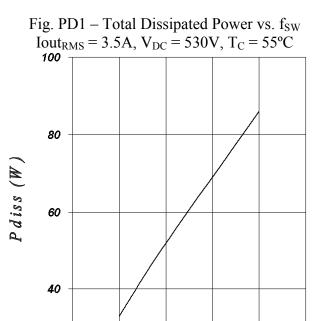


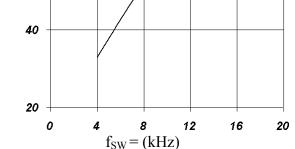


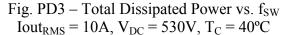
ISR Rectifier

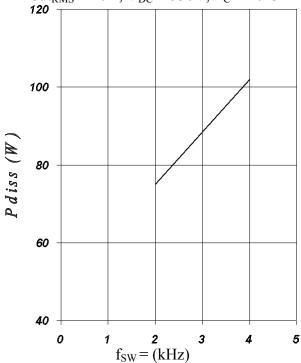


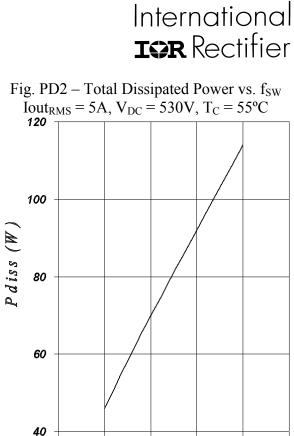






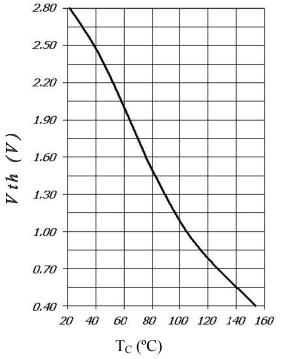




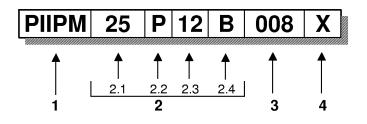


0 8 12 16 20 4 $f_{SW} = (kHz)$

Fig. TF1 – Thermal Sensor Voltage Feedback vs. Base-plate Temperature



PIIPM family part number identification

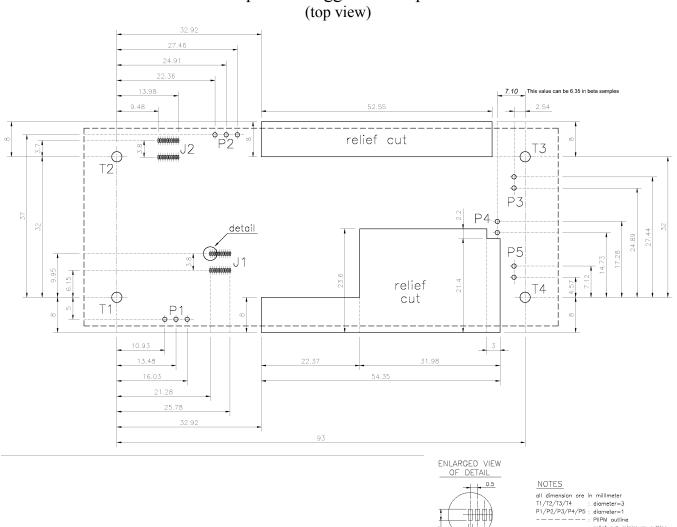


- 1- Device type (Programmable Isolated Intelligent Power Module)
- 2- Power package code 2.1- Current rating Code [A] 2.2- Sensing Resistors configuration P = on 3 phases Q = on 2 phases (*)R = on 1 phase (only for Matrix config.) (*) E = on 3 emitters F = on 2 emitters (*)G = on 1 emitter (*)2.3- Voltage rating Code [V/100] 06 = 600V12 = 1200V 2.4- Power Module configuration code A = Bridge brake (*) B = Inverter C = Inverter + brake D = BBI (Bridge Brake Inverter) M = Matrix (*) 3- EDB configuration code See detailed Block Diagram 4- Status code X = Sample (product with pre-qualification approval) Mating connectors included in the box blank = Fully qualified product

note: *= contact factory for availability

PIIPM25P12B008

127147 02 - Oct



Top board suggested footprint

International

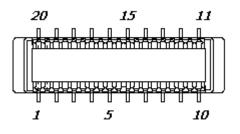
ICR Rectifier

RS422 and JTAG Connectors mapping

These connectors do not have any orientation tag; please check their Pin 1 position on Power Module Frame Pins Mapping before inserting mate part.

JTAG and RS422 on-board connectors

Top view

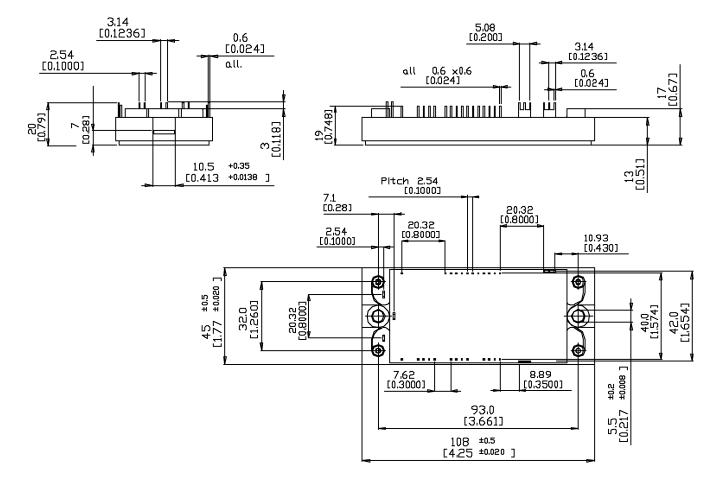


Molex 53916-0204 mates with 54167-0208 or 52991-0208

relief cut minimum outline

0.3

PIIPM25P12B008 case outline and dimensions



Data and specifications subject to change without notice This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web Site.

International **IGR** Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, Tel: (310) 3252 7105 TAC Fax: (310) 252 7309 Visit us at www.irf.com for sales contact information 02 - Oct

Data and specifications subject to change without notice. Sales Offices, Agents and Distributors in Major Cities Throughout the World. © 2003 International Rectifier - Printed in Italy 10-02 - Rev. 3.0